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Compositional dependence of ferromagnetic and magnetoelectric effect properties in BaTiO₃–BiFeO₃–LaFeO₃ solid solutions†

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Multiferroic ceramics consisting of barium titanate (BaTiO₃, BT), bismuth ferrite (BiFeO₃, BFO), and lanthanum ferrite (LaFeO₃, LFO), namely (1 – x)(0.96BaTiO₃–0.04BiFeO₃)–xLaFeO₃ (BT–BFO–xLFO, where x = 0.1–0.5), were synthesized by the sol–gel method. The crystal structure, microstructure, and dielectric, ferromagnetic, and magnetoelectric properties of the ceramics were systematically investigated. Structural analysis of BT–BFO–xLFO solid solution showed a pure perovskite structure. The Rietveld refined XRD data fitted well with an orthorhombic structure (*Pbnm* space group). BT–BFO–0.4LFO and BT–BFO–0.5LFO exhibited initial dielectric constants of 2114 and 1741, respectively, at 20 Hz, followed by fast decay with increasing frequency. In comparison, the BT–BFO–xLFO ceramics with x = 0.1–0.3 showed excellent stability. Remarkably improved ferromagnetic properties were obtained for BT–BFO–0.4LFO, and the remnant magnetization increased from 0.008 to 0.666 emu g^{–1} when x was increased from 0.1 to 0.4. The maximum value of the magnetoelectric coefficient reached 354 mV (cm^{–1}·Oe^{–1}) for the ceramic with x = 0.4 at 1000 kHz and 1 kOe.

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1. Introduction

The coexistence of ferroelectric, ferromagnetic, and ferroelastic ordering in multiferroic materials makes them popular materials for transformers, sensors, and information storage.¹ In multiferroics, a magnetoelectric (ME) material is one whose ferroelectric and ferromagnetic order parameters are coupled.^{2–5} There are a few ME multiferroic materials which have attracted the attention of many researchers.

The rhombohedral perovskite bismuth ferrite (BiFeO₃, BFO) is a single-phase ME material. It has high Neel ($T_N = 370$ °C) and Curie temperatures ($T_C = 830$ °C).^{6,7} However, two factors hinder its use in applications: persistent formation of impurity phases and large leakage current.⁸ Therefore, many studies have been carried out to improve the electric insulation and prevent the formation of impurity phases, including partial substitution of A sites^{9,10} and B sites¹¹ and the formation of solid solutions of

BiFeO₃ with other ABO₃-type perovskites.^{12–14} The solid solution of barium titanate (BaTiO₃, BT) and BFO (BT–BFO) has been extensively studied.^{14–17}

In our previous work,¹⁸ we reported the fabrication of binary solid solutions of (1 – x)BT–xBFO (x = 0–0.07). The ceramic with BFO content of x = 0.04 exhibited enhanced ferroelectric properties with remnant polarization (P_r) of 16.74 μC cm^{–2}. Although the BT–BFO system possesses high ferroelectric properties, its use in practical applications still faces many issues. For example, BT–xBFO ceramics exhibit extremely low ferromagnetic properties, and the ceramic with x = 0.04 exhibits the highest magnetoelectric coupling coefficient of 298.8 mV (cm^{–1}·Oe^{–1}) at 900 kHz and 1000 Oe, which is too small for practical applications. In order to improve the ferromagnetic properties, many different modifications were carried out on the BT–BFO system. Jiang *et al.*¹⁹ found that the ferromagnetism of the materials was greatly enhanced by doping them with SmCoO₃, which resulted in a remnant magnetism (M_r) of 0.136 emu g^{–1} for 0.75BiFeO₃–0.25BaTiO₃ and 0.389 emu g^{–1} for 0.68BiFeO₃–0.25BaTiO₃–0.07SmCoO₃. Tian *et al.*⁹ reported that Eu-modified (1 – x)BiFeO₃–xBaTiO₃ ceramics exhibited improved M_r of 0.136 emu g^{–1}. Other ceramics like BiFeO₃–ReFeO₃–BaTiO₃ (Re = Dy, Pr, or La)²⁰ were also investigated systematically, and the most remarkable ferromagnetic ferroelectrics obtained in this study were 0.65BiFeO₃–0.025DyFeO₃–0.325BaTiO₃ ($P_r = 5$ μC cm^{–2}, $M_r = 0.1$ emu g^{–1}) and 0.475BiFeO₃–0.05LaFeO₃–0.475BaTiO₃ ($P_r = 3.2$ μC cm^{–2}, $M_r = 0.2$ emu g^{–1}). Double modifications of

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the BT-BFO system were carried out using PrFeO_3 and DyFeO_3 ,²¹ producing $0.4\text{BiFeO}_3-0.1\text{PrFeO}_3-0.1\text{DyFeO}_3-0.4\text{BaTiO}_3$ with $P_r = 4.2 \mu\text{C cm}^{-2}$ and $M_r = 0.04 \text{ emu g}^{-1}$.

Lanthanum ferrite (LaFeO_3 , LFO) is an orthorhombically distorted perovskite structure with antiferromagnetic characteristics.^{22–24} It exhibits a high Neel temperature ($T_N = 467 \text{ }^\circ\text{C}$) and a colossal dielectric constant.²⁵ Since the radii of a La^{3+} ion (1.032 Å) and a Ba^{2+} ion (1.35 Å) are almost the same, LFO is a promising candidate for improving the ferromagnetic properties of ME materials. The addition of the antiferromagnetic LFO into the BT-BFO system is expected to improve the ferromagnetic and magnetoelectric properties.

Therefore, $(1-x)(0.96\text{BaTiO}_3-0.04\text{BiFeO}_3)-x\text{LaFeO}_3$ (BT-BFO- x LFO) ($x = 0.1-0.5$) ternary system was synthesized in this work, and its structure, microstructure, dielectric properties, ferromagnetic properties, and magnetoelectric coupling properties were studied systematically.

2. Experimental

A series of $(1-x)(0.96\text{BaTiO}_3-0.04\text{BiFeO}_3)-x\text{LaFeO}_3$ (BT-BFO- x LFO) ($x = 0.1-0.5$) multiferroic materials were prepared using the sol-gel method. Stoichiometric amounts of $\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$ (>99.0%), $\text{Fe}(\text{NO}_3)_3 \cdot 9\text{H}_2\text{O}$ (>98.5%), $\text{Ba}(\text{OH})_2 \cdot 8\text{H}_2\text{O}$ (>98.0%), $\text{Ti}(\text{OC}_4\text{H}_9)_4$ (>98.0%), and $\text{C}_6\text{H}_8\text{O}_7 \cdot \text{H}_2\text{O}$ (>99.5%) were dissolved in a mixture solvents ($\text{C}_2\text{H}_6\text{O}$ (>95.0%) : $\text{C}_2\text{H}_6\text{O}_2$ (>99.0%) = 3 : 7) to form a clear solution. The solutions were first stirred for 2 h at $25 \text{ }^\circ\text{C}$, then dried at $100 \text{ }^\circ\text{C}$ in a furnace and calcined at $750 \text{ }^\circ\text{C}$ for 3 h. After the calcined fine powders were sieved, the powders mixed with a 5 wt% polyvinyl alcohol binder solution and pressed into pellets. These pellets were heated at $500 \text{ }^\circ\text{C}$ for 3 h to eliminate the binder before they were sintered at $1300 \text{ }^\circ\text{C}$ for 2 h. Silver electrodes were fired on both surfaces at $600 \text{ }^\circ\text{C}$ for 30 min.

The crystalline structure of the ceramics was measured using X-ray diffraction (XRD; SmartLab, Rigaku, Japan). The microstructures and the corresponding selected-area electron diffraction were observed by scanning electron microscopy (SEM; ZEISS SUPRA-55, Zeiss, Germany) and transmission electron microscopy (TEM; Tecnai G2 F20, FEI, USA). The frequency dependence of the dielectric constant and dielectric loss was studied using a LCR meter (Agilent E4980A, Agilent Technologies Inc., Canada). The leakage-current density was tested by Keithley electrometer (6517B, Keithley Instruments Inc., USA). The ferroelectric hysteresis loops were measured at 1 kHz and room temperature with a Radiant Multiferroic tester (Multiferroic, Radiant Technologies Inc., USA). The magnetic hysteresis ($M-H$) loops were measured using a magnetic measurement instrument (JDAW-2000C&D, Changchun Yingpu Magnetoelectricity Technology Co., China). The magnetoelectric coefficient was determined using the direct-current (DC) static with various magnitudes magnetic field and frequencies.

3. Results and discussion

To reveal the structure of BT-BFO- x LFO ($x = 0.1-0.5$) ceramics, the XRD patterns are shown in Fig. 1. As shown in Fig. 1(a), all

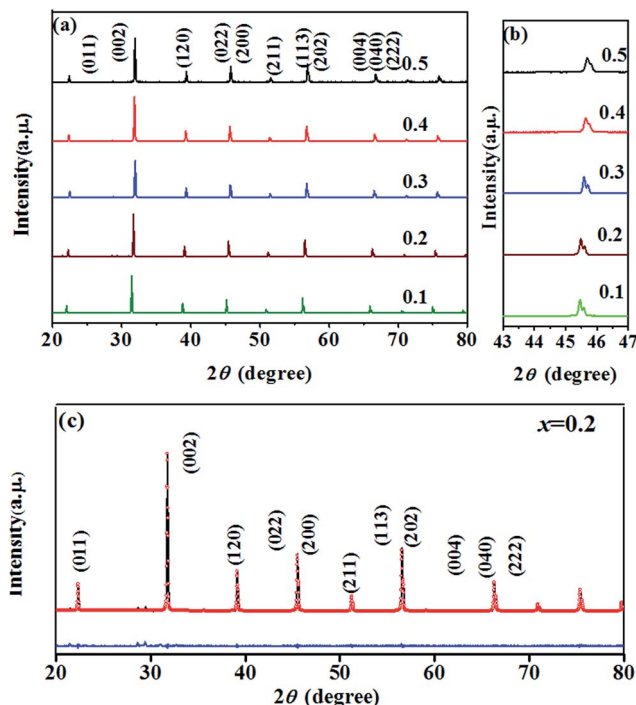


Fig. 1 XRD patterns of the BT-BFO- x LFO ($x = 0.1-0.5$) ceramics sintered at $1300 \text{ }^\circ\text{C}$ in the 2θ range of (a) $20-80^\circ$ (b) $43-47^\circ$ and (c) Rietveld refined of $x = 0.2$.

samples display a pure perovskite structure with orthorhombic phase peaks. The (022) and (200) peaks are magnified in Fig. 1(b), and it can be seen that the peaks shift toward higher 2θ with an increase of x . This can be attributed to the ionic radius of La^{3+} (1.032 Å) is smaller than Ba^{2+} (1.35 Å). Rietveld refinements are carried out using FullProf software (Institut Laue-Langevin, France) to help us further understand the structural characteristics of the BT-BFO- x LFO ($x = 0.1-0.5$) ceramics; which are shown in Fig. 1(c) and S1.† The Rietveld refined XRD data was well fitted with orthorhombic structure ($Pbnm$ space group). The variations in the lattice parameters obtained from the XRD data are shown in Table 1. For all of the refinements, small values are obtained for the reliability of the weight pattern ($R_{\text{wp}} = 6.13-9.74\%$, *i.e.* $R_{\text{wp}} < 15\%$) and the goodness-of-fit indicator ($S = 1.13-1.55$, *i.e.* $S < 2$), suggesting a good match between the observed and calculated patterns.

Table 1 Refined structural parameters of BT-BFO- x LFO ($x = 0.1-0.5$) ceramics

x	Lattice parameters			R factors (%)	
	a (Å)	b (Å)	c (Å)	R_{wp}	S
0.1	5.6482	5.6448	3.9904	8.02	1.42
0.2	5.6360	5.6339	3.9824	9.74	1.55
0.3	5.6241	5.6283	3.9758	7.72	1.19
0.4	5.6103	5.6070	3.9680	6.13	1.14
0.5	5.6036	5.5988	3.9584	6.13	1.13



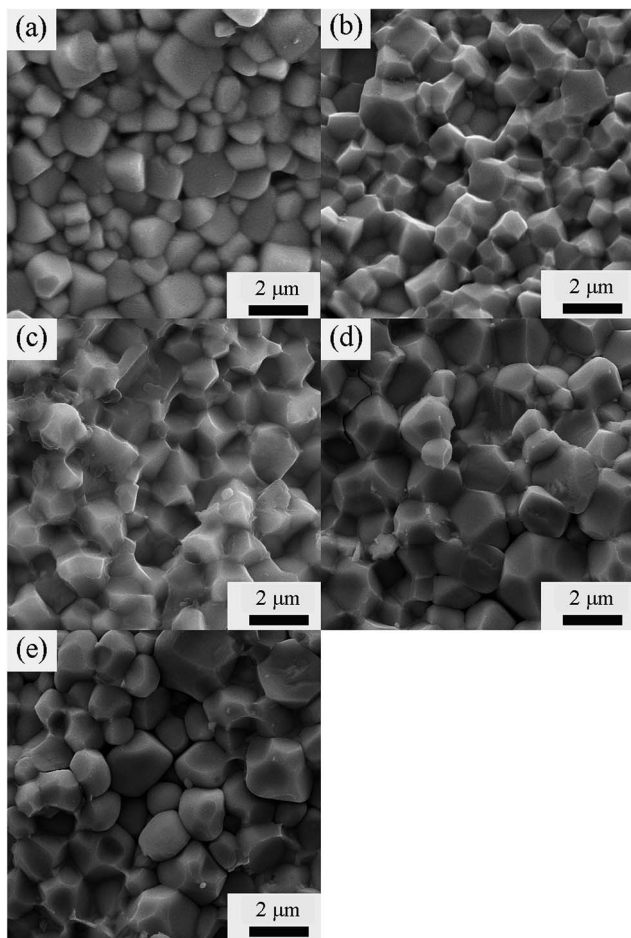


Fig. 2 SEM images of the BT-BFO-*x*LFO ceramics sintered at 1300 °C with (a) *x* = 0.1, (b) *x* = 0.2, (c) *x* = 0.3, (d) *x* = 0.4, (e) *x* = 0.5.

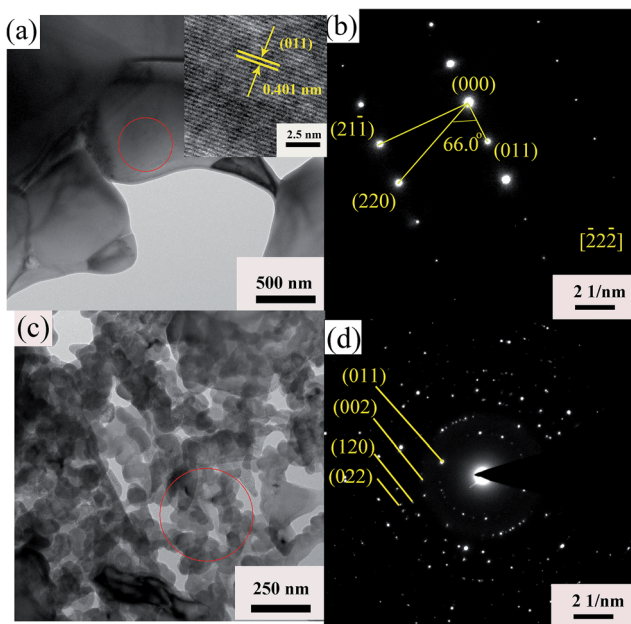


Fig. 3 (a, c) TEM bright field images and (b, d) corresponding electron diffraction patterns of BT-BFO-0.2LFO ceramics.

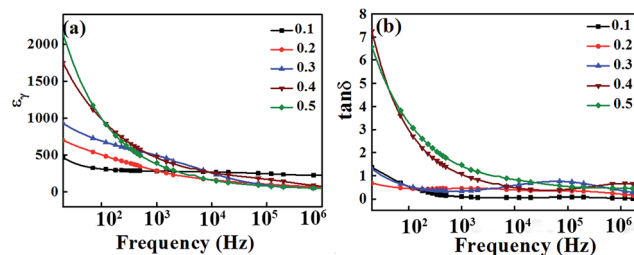


Fig. 4 (a) Relative dielectric constant ϵ_r and (b) dielectric loss $\tan \delta$ of BT-BFO-*x*LFO (*x* = 0.1–0.5) ceramics sintered at 1300 °C.

To reveal the fracture surface of the BT-BFO-*x*LFO (*x* = 0.1–0.5) ceramics, the SEM images are shown in Fig. 2. The samples exhibit dense and homogeneous microstructures. To further confirm the crystal structure and grain size of the BT-BFO-*x*LFO ceramics, TEM has been used for characterization. Selected typical composition of LFO with 0.2, namely BT-BFO-0.2LFO. Fig. 3 shows the bright-field images and corresponding SAED patterns of BT-BFO-0.2LFO. It exhibits two types of grains: larger grains with the apparent average values in the range of 1–2 μm and the smaller grain size with the nanometer sizes, as shown in Fig. S3(a and b).† Even though their grains are different, their structure are the same just as shown in Fig. 3(b and d). The high-resolution TEM (HRTEM) image in Fig. 3(a) shows a uniform lattice fringe with a *d*-spacing of 0.401 nm, which is a good match to the (011) plane of the orthorhombic lattice. The interplanar spacing values (*d*) of the selected area electron diffraction (SAED) (Fig. 3(b) and (d)) patterns well matched with the standard values calculated from the XRD. These results confirm the orthorhombic structure of the BT-BFO-0.2LFO sample.

The relative dielectric constant ϵ_r and the dielectric loss $\tan \delta$ of the BT-BFO-*x*LFO (*x* = 0.1–0.5) ceramics are shown in Fig. 4. It is evident that both ϵ_r and $\tan \delta$ decreases with increasing frequency. In the low-frequency range, ϵ_r and $\tan \delta$ has higher values, but both gradually decreases as the frequency increased from 20 to 10⁴ Hz. At frequencies above 10⁴ Hz, the decrease in ϵ_r and $\tan \delta$ became slow and keep constant at 10⁵ Hz for all compositions. These variations occurred due to the dipoles could easily change in the lower frequencies, but they did not have sufficient time to align at higher frequencies, thus

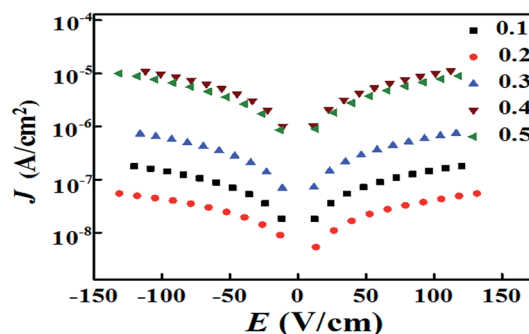


Fig. 5 Leakage current density of BT-BFO-*x*LFO (*x* = 0.1–0.5) ceramics sintered at 1300 °C.



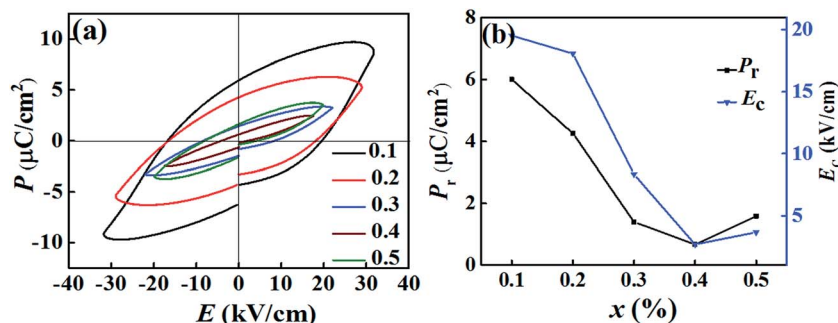


Fig. 6 (a) P - E loops of BT-BFO- x LFO ($x = 0.1$ - 0.5) ceramics sintered at $1300\text{ }^{\circ}\text{C}$. (b) Composition dependences of the remnant polarization P_r and coercive field E_c for the BT-BFO- x LFO ($x = 0.1$ - 0.5) ceramics.

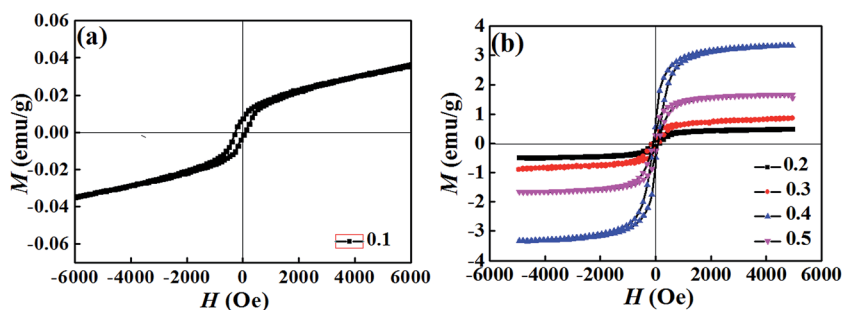


Fig. 7 M - H loops of BT-BFO- x LFO ($x = 0.1$ - 0.5) ceramics sintered at $1300\text{ }^{\circ}\text{C}$ with (a) $x = 0.1$, (b) $x = 0.2$ - 0.5 .

resulting in the decreases in ϵ_r and $\tan \delta$. When the frequency was 20 Hz, the initial dielectric constants of BT-BFO-0.4LFO and BT-BFO-0.5LFO are 2114 and 1741, respectively; however, they decrease quickly with increasing frequency. The ceramics with $x = 0.1$ - 0.3 showed much more stable dielectric constants. As shown in Fig. 4(b), the measured $\tan \delta$ had low values of <1.0 for ceramic samples of all compositions from 10^4 Hz to 10^6 Hz.

To reveal the electric insulation of the ceramics, the leakage current density (J) is shown in Fig. 5. The ceramic with $x = 0.1$ exhibited low J values of 10^{-6} - 10^{-7} A cm^{-2} . For the ceramic with $x = 0.2$, the leakage-current density was 10^{-7} - 10^{-8} A cm^{-2} , which was decreased almost one order of magnitude. However, for ceramic samples with $x = 0.3$ - 0.5 , the transformation of Fe ions in LaFeO_3 from Fe^{3+} to Fe^{2+} created oxygen vacancies, which resulted in high conductivity and J linearly increased to 10^{-5} - 10^{-6} A cm^{-2} .

In order to study the ferroelectric behavior of the BT-BFO- x LFO ($x = 0.1$ - 0.5) ceramics, the polarization hysteresis (P - E) loops were measured at a frequency of 1 kHz, are shown in Fig. 6. It has been known that it is difficult to obtain well-saturated ferroelectric loops when the leakage currents are high. Therefore, our system was never left to reach full saturation and the polarization values generally remained low. The remnant polarization of the BT-BFO- x LFO ($x = 0.1$ - 0.5) ceramics decreased from 6.00 to 0.67 $\mu\text{C cm}^{-2}$ as x increased from 0.1 to 0.5. During the measurements, higher fields were not applied because of the high leakage-current densities of the samples.

Substitution is known to be an effective way to enhance the ferromagnetic properties of BFO. To investigate the effect of substitution on the magnetic properties, magnetic-field (M - H) hysteresis loops of the BT-BFO- x LFO ($x = 0.1$ - 0.5) ceramics are shown in Fig. 7. All the ceramic samples exhibited typical magnetization hysteresis loops, suggesting that they simultaneously possessed ferromagnetism and ferroelectricity. Fig. 7(a) indicates that the ceramic with $x = 0.1$ exhibited weak ferromagnetism, and the observed remnant magnetization (M_r) and coercive field (H_c) were 0.008 emu g^{-1} and 277 Oe, respectively. For the ceramic with $x = 0.4$, the ferromagnetism was significantly higher, with M_r of 0.666 emu g^{-1} and H_c of 142 Oe. However, excess LFO degraded the ferromagnetism of the ceramics. For the ceramic with $x = 0.5$, M_r decreased to 0.300 emu g^{-1} and H_c had a value of 161 Oe. Generally speaking, the magnetic properties of LaFeO_3 originate from the interactions between the magnetic moments of iron and the rare-earth atom La.²⁶ When the amount of LFO was increased, the mismatch in ionic radii (Fe versus Ti) and the multiple valance states of Ba^{2+} / La^{3+} or Fe^{3+} / Ti^{4+} decrease the remnant magnetization.

The observation of ferromagnetic and ferroelectric properties simultaneously indicate existing magnetoelectric coupling in this compound. Fig. 8 shows the magnetoelectric coefficient (α_{ME}) at various DC magnetic fields and frequencies for the BT-BFO- x LFO ($x = 0.1$ - 0.5) ceramics. The value of α_{ME} increased when the frequency increased from 0 to 1000 kHz, but it exhibited weak dependence on the magnetic field except $x = 0.5$. The 3D image of BT-BFO-0.4LFO ceramic in Fig. 8(c) exhibits the same tendency. In Fig. 8(a), the ceramic with $x =$



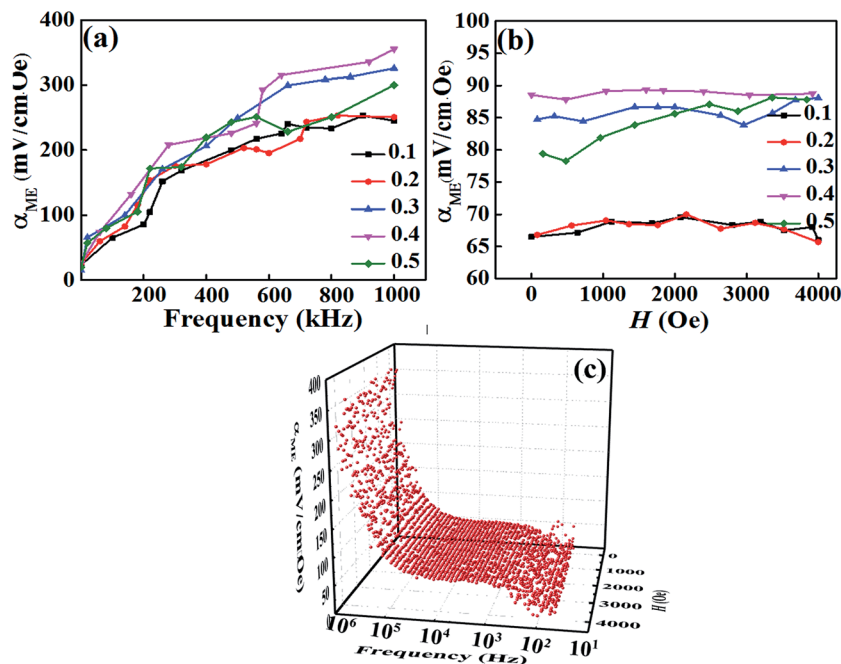


Fig. 8 Magnetoelectric coefficient α_{ME} for various applied (a) frequencies and (b) dc magnetic field of the BT-BFO-xLFO ($x = 0.1-0.5$) ceramics sintered at 1300 °C and (c) 3D image of BT-BFO-0.4LFO ceramic.

0.1 exhibited a low α_{ME} of 252 mV (cm⁻¹·Oe⁻¹) at the frequency 900 kHz, which can be ascribed to the poor ferromagnetic property (Fig. 7(a)). After the addition of more LFO ($x = 0.4$), the observed α_{ME} significantly increased to the maximum value of 354 mV (cm⁻¹·Oe⁻¹) at 1000 kHz and 1000 Oe. Compared with BFO-BT-0.1LFO, the α_{ME} value of BFO-BT-0.4LFO was 40.48% higher owing to the better ferroelectric and ferromagnetic properties. For the ceramic with $x = 0.5$, the observed α_{ME} was slightly lower, with a value of 300 mV (cm⁻¹·Oe⁻¹) at 1000 kHz and 1000 Oe. The sample exhibited weak ME behaviour because of the significantly degraded ferromagnetic property.

4. Conclusion

A large magnetoelectric coefficient α_{ME} of 354 mV (cm⁻¹·Oe⁻¹) associated with high remnant magnetization M_{r} of 0.666 emu g⁻¹ is reported in BT-BFO-0.4LFO ceramics. LFO doping has significantly improved ferromagnetic and magnetoelectric properties. Certainly, the present strategy is transferable. We believe that it would inspire plentiful researches on tailoring performance by means of properly modified.

Conflicts of interest

There are no conflicts to declare.

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